Onsemi

100 V, 2.0 A, Low V_{CE(sat)} **PNP** Transistor NSS1C200L, NSV1C200L

onsemi's e²PowerEdge family of low V_{CE(sat)} transistors are miniature surface mount devices featuring ultra low saturation voltage (V_{CE(sat)}) and high current gain capability. These are designed for use in low voltage, high speed switching applications where affordable efficient energy control is important.

Typical applications are DC-DC converters and power management in portable and battery powered products such as cellular and cordless phones, PDAs, computers, printers, digital cameras and MP3 players. Other applications are low voltage motor controls in mass storage products such as disc drives and tape drives. In the automotive industry they can be used in air bag deployment and in the instrument cluster. The high current gain allows e²PowerEdge devices to be driven directly from PMU's control outputs, and the Linear Gain (Beta) makes them ideal components in analog amplifiers.

Features

NSV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable

These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

MAXIMUM RATINGS (T_A = 25 C)

Rating	Symbol	Max	Unit
Collector-Emitter Voltage	V _{CEO}	-100	Vdc
Collector-Base Voltage	V _{CBO}	-140	Vdc
Emitter-Base Voltage	V _{EBO}	-7.0	Vdc
Collector Current – Continuous	۱ _C	-2.0	А
Collector Current – Peak	I _{CM}	-3.0	А

-100 VOLTS, 2.0 AMPS PNP LOW V_{CE(sat)} TRANSISTOR



SOT-23 NSS1C200LT1G, 3000/Tape & Reel NSV1C200LT1G (Pb-Free)

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

	$R_{\theta JA}$ (Note 2)	176	C/W
Junction and Storage Temperature Range	T _J , T _{stg}	–55 to +150	С

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

FR-4 @ 100 mm², 1 oz. copper traces.
FR-4 @ 500 mm², 1 oz. copper traces.

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ELECTRICAL CHARACTERISTICS (T_A = 25 C unless otherwise noted)

Characteristic	Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS					

V

Collector – Emitter Breakdown Voltage $(I_{C} = -10 \text{ mAdc}, I_{B} = 0)$

NSS1C200L, NSV1C200L



NSS1C200L, NSV1C200L





SOT 23 (TO 236) 2.90x1.30x1.00 1.90P CASE 318 ISSUE AU

DATE 14 AUG 2024

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	STYLE 6: PIN 1. BASE 2. EMITTER 3. COLLECTOR	STYLE 7: PIN 1. EMITTER 2. BASE 3. COLLECTOR	STYLE 8: PIN 1. ANODE 2. NO CONNECTION 3. CATHODE		
STYLE 9:	STYLE 10:	STYLE 11:	STYLE 12:	STYLE 13:	STYLE 14:
PIN 1. ANODE	PIN 1. DRAIN	PIN 1. ANODE	PIN 1. CATHODE	PIN 1. SOURCE	PIN 1. CATHODE
2. ANODE	2. SOURCE	2. CATHODE	2. CATHODE	2. DRAIN	2. GATE
3. CATHODE	3. GATE	3. CATHODE-ANODE	3. ANODE	3. GATE	3. ANODE
STYLE 15:	STYLE 16:	STYLE 17:	STYLE 18:	STYLE 19:	
PIN 1. GATE	PIN 1. ANODE	PIN 1. NO CONNECTION	PIN 1. NO CONNECTION	PIN 1. CATHODE	
2. CATHODE	2. CATHODE	2. ANODE	2. CATHODE	2. ANODE	
3. ANODE	3. CATHODE	3. CATHODE	3. ANODE	3. CATHODE-ANODE	
	STYLE 22: PIN 1. RETURN 2. OUTPUT 3. INPUT	STYLE 23: PIN 1. ANODE 2. ANODE 3. CATHODE 3.			

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